

**SURFACE MOUNT GLASS PASSIVATED
HIGH EFFICIENCY SILICON RECTIFIER**
VOLTAGE RANGE 50 to 1000 Volts CURRENT 3.0 Amperes

FEATURES

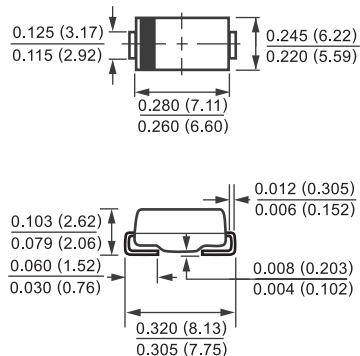
- * Glass passivated device
- * Ideal for surface mounted applications
- * Low leakage current
- * Metallurgically bonded construction
- * Mounting position: Any
- * Weight: 0.24 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.



DO-214AB



Dimensions in inches and (millimeters)

MAXIMUM RATINGS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

RATINGS	SYMBOL	HFM301	HFM302	HFM303	HFM304	HFM305	HFM306	HFM307	HFM308	UNITS
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	300	400	600	800	1000	Volts
Maximum RMS Volts	V _{RMS}	35	70	140	210	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	300	400	600	800	1000	Volts
Maximum Average Forward Current at TA = 50°C	Io	3.0								Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	200					150			Amps
Typical Junction Capacitance (Note 2)	Cj	70					50			pF
Operating and Storage Temperature Range	TJ, TSTG	-65 to +175								°C

ELECTRICAL CHARACTERISTICS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

CHARACTERISTICS		SYMBOL	HFM301	HFM302	HFM303	HFM304	HFM305	HFM306	HFM307	HFM308	UNITS
Maximum Forward Voltage at 3.0A DC		V _F	1.0			1.3		1.7			Volts
Maximum Full Load Reverse Current, Full cycle Average T _A =55°C		I _R	50								uAmps
Maximum DC Reverse Current at	@ T _A = 25°C		10								uAmps
Rated DC Blocking Voltage	@ T _A = 125°C		150								uAmps
Maximum Reverse Recovery Time (Note 1)		trr	50					75			nSec

NOTES : 1. Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$.

2. Measured at 1 MHz and applied reverse voltage of 4.0 volts.

RATING AND CHARACTERISTIC CURVES (HFM301 THRU HFM306)

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

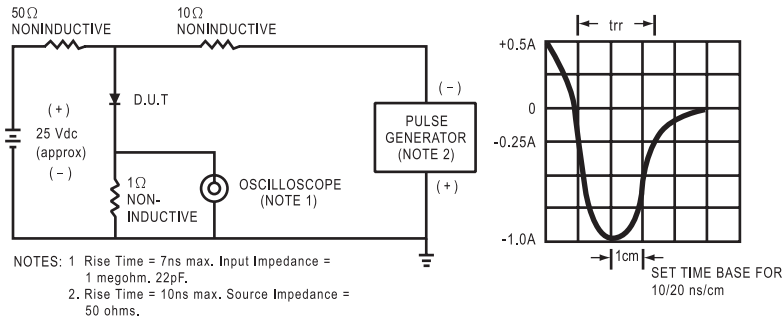


FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

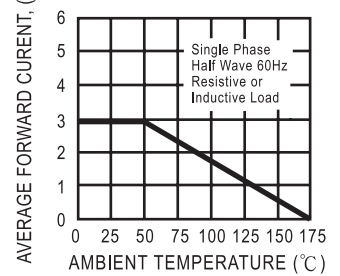


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

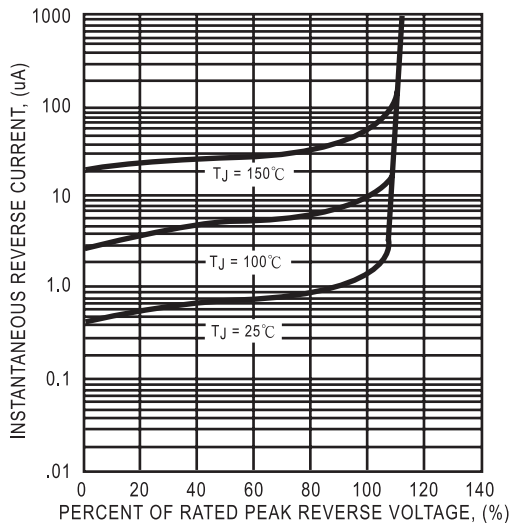


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

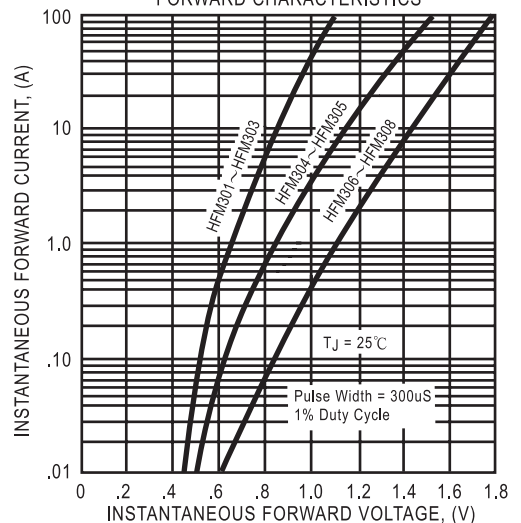


FIG. 5 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

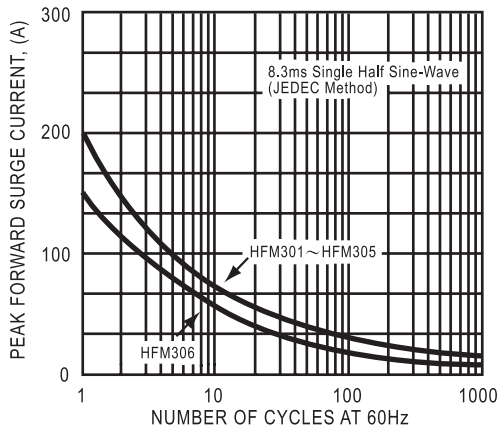


FIG. 6 - TYPICAL JUNCTION CAPACITANCE

